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Abstract

The 1200°C oxidation behavior of NiAl was examined at various levels of sulfur and zirconium dopants to test the possibility of a critical S/Zr ratio required for adhesion. Cyclic furnace testing for 200 1-hr cycles and interrupted testing for 500 hr were used as screening tests. Pure NiAl and NiAl(Zr) with 0.14 at.% Zr were chosen as model base compositions; they exhibited normal, slow-growing scales ($3 \text{ mg}\cdot\text{cm}^{-2}$) with excellent adhesion for the Zr-doped alloys. NiAl with about 120 ppma S exhibited a substantial weight loss ($-20 \text{ mg}\cdot\text{cm}^{-2}$) in cyclic tests and a very large weight gain ($+60 \text{ mg}\cdot\text{cm}^{-2}$) in interrupted tests. The major surface phase remained as $\alpha\text{-Al}_2\text{O}_3$. Sulfur doping the NiAl(Zr) alloy caused massive weight gains of $80\text{-}100 \text{ mg}\cdot\text{cm}^{-2}$, swelling, cracking, and nearly complete conversion into NiAl_2O_4 and $\alpha\text{-Al}_2\text{O}_3$. The initial objective of determining critical S/Zr ratios for adhesion was therefore unattainable. Initiation of the catastrophic attack was examined after a 10 hr exposure, revealing a few sites of broad, raised, and cracked ridges. In cross-section, the ridges appeared as nodular intrusions, with a complex, fractal, oxide-metal interface. They were primarily alumina (with occasional entrapped islands of NiAl_2O_4 or pure Ni metal). They possessed a unique microstructure consisting of $0.3 \text{ }\mu\text{m}$ lamellae, separated by $0.1 \text{ }\mu\text{m}$ open channels. This allowed for rapid growth controlled by gaseous diffusion. The microstructure is discussed in terms of SO_2 evolution and a sulfur-driven de-passivation process.

Introduction

Alumina scale adhesion to (Ni,Co,Fe)CrAl is greatly improved by small additions of reactive elements. According to the sulfur model of scale adhesion, the primary role of the dopants is to getter sulfur impurities in the metal and preclude their segregation at the oxide-metal interface and subsequent degradation of the oxide-metal bond [1]. In various tests of this theory, good adhesion has been shown to result by reducing the sulfur content [2,3]. For some alloys, behavior equivalent to that of reactive element doping was obtained by hydrogen annealing to extremely low sulfur levels (0.1 ppmw) [4,5]. Conversely, it has been shown that sulfur additions to an adherent, doped alloy system can destroy adhesion [6-9]. In our previous work we attempted to both show that sulfur additions could destroy adhesion for NiCrAl+Zr alloys and to determine the critical S/Zr content for adhesion for a wide range of dopant levels. In order to extend this work to the present study on NiAl, a few levels of sulfur were added to NiAl with and without Zr dopants.

A study of sulfur-doped NiAl(Y) has shown that 270 ppma S increased the k_p at 900°C by about a factor of 3 [10]. Sputter profiling Auger spectroscopy revealed sulfur segregation at the oxide-metal interface, somewhat mitigated by the presence of Y. Another Auger study found strong sulfur segregation to interfacial voids for NiAl + 90 ppma S at 1000°C [11]. And a TEM/STEM

study of NiAl + 270 ppma S at 950°C revealed sulfur segregation at interfacial and included pores, as well as at oxide grain boundaries and intact scale-metal interfaces [12]. This study found a 4x increase in scale thickness and increased porosity due to sulfur doping. Accelerated (linear) internal oxidation was observed for NiAl oxidized in low pO_2 atmospheres in the presence of sulfur impurities or 1% H_2S [13]. Excessive scale porosity at 1200°C had been noted for one of the present NiAl alloys studied (120 ppma S) [14].

The present study examines the effects of adding 0.05% S to pure NiAl and 0.14% S to NiAl + 0.14% Zr. The former is intended to show only the effects of a large amount of sulfur; the second alloy is intended to show whether a stoichiometric amount of S and Zr affects adherence. It is part of a larger study examining various S/Zr contents, but limited here to focus on a few key issues arising from the scale microstructures.

Experimental

Drop cast buttons of NiAl (\pm S, Zr) alloys were made by double arc melting. The intended alloy compositions and analyses by XRF and GDMS (x-ray fluorescence and glow discharge mass spectroscopy) are shown in Table I. It appears that a large amount of sulfur may be lost during processing. However the residual amount (120 ppma by GDMS, 150-300 ppma by combustion extraction analysis (Leco CS 444), and 400 ppma by XRF) is still very large compared to the nominal impurity level (1.5 ppma). (Relative standard deviations are on the order of 15% for XRF, 0.5% for combustion, and 25% for GDMS). The Ni and Al contents remained reasonably close to stoichiometric. The co-doped alloy exhibited an anomalous network, presumably breaks in the carbon film, and many Zr-S containing precipitates, Fig. 1. Because of the small size, microprobe analyses of these particles always revealed high Ni and Al levels, Table II. The S/Zr ratios varied from 0.01 to 0.6, suggesting that the particles were always hyperstoichiometric with respect to ZrS or ZrS_2 . XRD analyses of as-received castings also indicated the possibility of Ni_2AlZr .

Oxidation of 600 grit polished coupons was performed in air at 1200°C. Cyclic oxidation (1-hr cycles) was performed for 200 hours; interrupted oxidation was performed at 1, 10, 125, and 500 hr. The scale surfaces were examined by XRD and SEM. Alloy 3 (0.14 S, 0.14 Zr) was examined in cross-section after just 10 hr of isothermal oxidation to document the early stages of consumption.

Results

The cyclic oxidation weight change data is shown in Fig. 2. The undoped alloy exhibited some scale spallation to bare metal in an otherwise grey compact layer, amounting to -2.31 mg/cm^2 after 200 hr. The sulfur doped sample appeared white and less compact, although it also exhibited spalling to bare metal, amounting to -21.11 mg/cm^2 weight change after 200 hr. Finally the S/Zr co-doped sample gained 105.59 mg/cm^2 , appeared turquoise in color, and fractured into many pieces because of the stresses arising from excessive oxidation. The interrupted oxidation data is shown in Fig. 3, showing weight changes of -2.20 , 58.54 , and 104.23 for the same three alloys after 500 hr. This is very nearly the same response as before, however now the S-doped sample shows an excessive weight gain rather than a loss. It is apparent that this high level of sulfur doping has triggered a type of catastrophic oxidation.

Examination of the initial segments of the curves (first 80 hr cyclic, first 125 hr interrupted) suggest that linear oxidation rates were operative for the co-doped sample. The interrupted test also suggests a linear rate for the sulfur doped sample for the entire 500 hr. While excessive spalling for the sulfur doped sample is expected, the catastrophic linear growth rate is not. Also the co-doped sample actually had a higher catastrophic growth rate. There was no visual indication of interfacial spalling for all three samples, and no information on S or Zr effects on adhesion could be discerned. The task at hand is to explain the origin of these high rates.

The results of X-ray diffraction of the scale surfaces are shown in Table III. The scales on the undoped and sulfur-only doped samples consisted entirely of α - Al_2O_3 , whereas the scales on the co-doped sample were NiAl_2O_4 spinel and α - Al_2O_3 , with little difference between the cyclic and interrupted tests. While a higher oxidation rate might be expected for spinel scales on the co-doped samples, the XRD results do not explain the high rates on the sulfur-only doped sample.

The large weight change and the kinetic slowing after 125 hr for the co-doped sample suggest that this sample may be reaching total consumption after 500 hr, Fig. 3. From the reaction:



one can calculate the weights of the resultant products after complete reaction given the initial weight of the sample and the Ni, Al concentrations. For this sample, initially 1.58 gm, the amount of NiO product would be 1.40 gm and the amount of Al_2O_3 would be 0.90 gm. The total product was therefore calculated to be 2.31 gm, as compared to the measured 2.09 gm final weight, or ~90% converted on a weight change basis.

After just 10 hr of oxidation (isothermal), the S/Zr co-doped sample still gained 9.0 mg/cm^2 and the scale was determined by XRD to be primarily α - Al_2O_3 , with a minor amount of NiAl_2O_4 . Examination of the surface revealed essentially flat, dark grey regions of adherent oxide, with a network of ridges, perhaps decorating some grain boundaries. Occasional growth nodules also existed in isolation from the network. Details of such a ridge are shown in the SEM micrographs of Fig. 4. Figure 4(a) shows one leg of a ridge network, having severe cracking down the midrib or spline and bright outlines at the growth boundary between the ridge and unaffected scale. The highlighting arises from uplifted scale segments and spalling to bare metal at this boundary. In backscatter mode, Fig. 4(b), the ridge areas exhibit a finely spaced network of cracks (C), grey (Ni, Al)-rich oxide patches (S), and bright Ni-oxide nodules (N), all dispersed in a matrix of dark Al-oxide (from EDS).

These structures were analyzed in more detail from a polished cross-section. At low magnification, the ridge sections show very deep oxide intrusions with a complex growth front, cracks, and a number of dispersed phases, Figs. 5 and 6. The various phases were analyzed by standardless EDS, Table IV: the bright areas were entrapped islands of Ni metal, the main dark intrusions were alumina, and the grey patches were NiAl_2O_4 spinel. (The exact stoichiometry was not obtained and the apparent chemistry was somewhat dependent on accelerating voltage).

In the residual, peninsular metal regions, Al depletion was detected up to ~50 μm ahead of the oxide interface. In other areas ahead of the growth fingers, very little Al depletion was noted (43% Al remained at positions 2.5 and 9.5 μm ahead of the intrusion in Fig. 7(a), compared to

53% at the center of the sample). Moderate and uniform depletion is also suggested by the occurrence of martensitic striations to a depth of at least 50 μm ahead of these protrusions. NiAl martensite is possible only for aluminum levels above 30% [15].

The BSE images in Fig. 7 also illustrate the complex interface of the alumina intrusions with indications of porosity (Fig. 7(a)). The interface is further seen as a columnar structure of oxide fibrils and continuous porosity, Fig. 7(b), with lateral dimensions on the order of 0.1-0.3 μm . Finally, at low kV, even finer porosity (0.05 μm) can be discerned within the primary pore network, Fig. 8. The basic picture is that of a porous, nonprotective oxide growing into the metal so fast and irregularly that it encapsulates islands of unreacted metal. These eventually react with incoming oxygen and the adjacent alumina matrix to form isolated regions of mixed oxides (spinel).

The sulfur-only doped sample was also oxidized for an intermediate time (125 hr). The scale top surface (Fig. 9(a)) and bottom surface (Fig. 9(b)) both contained a high degree of porosity, again suggesting a nonprotective scale microstructure. However this scale does not appear to grow into the metal with the unstable interface characteristic of the S/Zr co-doped sample. The reasons for this and the lower weight gain compared to the co-doped sample are not clear.

Discussion

A model is now proposed to account for the extensive porosity that may give rise to the catastrophic growth rates. It is based on the consumption of a layer of NiAl in reacting with a given amount of oxygen and the reaction of the amount of sulfur contained in this layer to form SO_2 gas. For the density of alumina given as 3.98 gm/cm^2 and NiAl as 5.86 gm/cm^2 , it can be shown that for every 1 mg/cm^2 of weight gain (of oxygen):

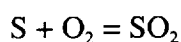
1. 124 mg/cm^2 of Al is reacted
2. 124 mg/cm^2 of Al_2O_3 is formed, (5.33 μm)
3. 57 mg/cm^2 of NiAl is affected, (6.00 μm).

Thus for a sulfur concentration of 120 ppma (88 ppmw), it can be shown that 9.8 moles/ cm^2 of sulfur are released for every 1 mg/cm^2 of oxygen gained. Using the ideal gas law and fixing P at 1 atm, then the volume of SO_2 can be calculated, yielding a gas layer thickness of 11.8 μm . This value is twice the thickness of the corresponding scale formed and strongly suggests that this amount of sulfur can contribute significantly to porosity. Conversely, if the relative volume of porosity, i.e., SO_2 , is fixed at 20%, then the corresponding pressure is calculated to be 11.1 atm., again implying a strong influence on pore formation. It should be recalled, however, that upwards of 100 mg/cm^2 weight gain was achieved, so the layer thickness calculated above for 1 mg/cm^2 weight gain must all be scaled upward by a factor of 100.

The general process can be described in terms of a growth interface schematic, Fig. 10. Here sulfur segregates to the oxide-metal interface as the NiAl layer reacts with oxygen to form Al_2O_3 . Some back diffusion of sulfur may accommodate the additional sulfur released, but sulfide growth was not observed and the matrix is already saturated. The build-up continues until it may react with incoming oxygen to form SO_2 . The SO_2 formed occupies a substantial volume at high pressure and prevents complete interface passivation from the Al_2O_3 . These depassivated regions

are then propagated as the relief valves for further sulfur evolution, developing into widespread porosity and microchannels. Depassivation may initially be produced by the intrinsic chemical properties of adsorbed sulfur and maintained by the physical gas evolution process. Chemical depassivation is widely observed in low temperature aqueous corrosion of transition metals having adsorbed or segregated sulfur monolayers [16]. The interconnected pores then serve as rapid paths for gaseous oxygen transport, allowing the oxidation process to be controlled by interface reaction kinetics (sulfur, oxygen, and aluminum surface rearrangements) rather than slow solid state diffusion in Al_2O_3 .

This situation is only valid if indeed the scale is completely porous and allows full access of oxygen to the interface with a $p\text{O}_2 = 0.2$ atm. If the scale seals off the interface, then the $p\text{O}_2$ is determined by the $\text{NiAl-Al}_2\text{O}_3$ equilibrium and will be less than $\sim 10^{-25}$ atm at 1200°C . For the reaction:



$$K = (p_{\text{SO}_2} / p_{\text{O}_2}) / a_{\text{S}}$$

It can be seen that a low value of $p\text{O}_2$ will define a low value of $p\text{SO}_2$. Thus the high gas pressures or volumes discussed above would not apply, and another means of creating porosity would be needed.

Rapid, linear, nonprotective growth of Al_2O_3 scales in NiAl has been observed at low $p\text{O}_2$ for 700 - 1000°C oxidation [13]. The presumed presence of sulfur impurities (from a Rhines pack) or in sulfur-containing gases (1% H_2S) was required to prevent the formation of a healing layer of Al_2O_3 . In some cases cones of oxide penetration were formed with a coarse lamellar structure of Ni metal and Al_2O_3 platelets. In other cases deep penetrating fingers of oxide grew into the alloy. This internal oxidation was predicated on the formation of a Ni -depletion zone ahead of the oxidation front.

There are similarities and differences with the present work. Nonprotective Al_2O_3 , a tortuous oxidation front, and sulfur as the responsible depassivating agent are all common factors. The requirement of a low $p\text{O}_2$ environment and a Ni -depletion zone for internal oxidation is not shared by the present study. Also no role of microporosity was apparent in the prior study. While sulfur plays an important role in both instances, the mechanism for rapid growth (internal oxidation versus microporosity) does not appear to be the same.

There are other instances of nonprotective scale growth due to rapid diffusion through structural features in other alumina and silica-forming systems. The 1200°C oxidation of AlN in moist oxygen was found to be linear, achieving 48 mg/cm^2 in 48 hr [17]. The microstructure contained a large fraction of fine 50 - 300 nm pores, Fig. 11. These presumably resulted from the evolution of N_2 gas released from the substrate and acted as fast diffusion paths for oxygen.

In low temperature (723°C) oxidation of NbAl_3 -based alloys, selective oxidation of aluminum allows Al_2O_3 to form, but back diffusion of Nb into the alloy does not occur rapidly enough [18]. The result is an internal oxide composed of intermingled 20 nm lamellae of denuded metallic Nb and $\alpha\text{-Al}_2\text{O}_3$. The oxide-metal interface and pure Nb act as rapid paths for oxygen diffusion. Thus low temperature, linear, accelerated oxidation is the result (e.g., 10 mg/cm^2 weight gain after 600 hr at 700°C).

Finally, MoSi_2 was found to exhibit linear, accelerated oxidation at 500°C , producing 2.3 mg/cm^2 in 50 hr [19]. The scale consisted of intermingled amorphous SiO_2 and nonprotective MoO_2 lamellae only 10 nm wide. Again the protective scale phase is discontinuous and nonhealing, and the product microstructure contains ultra-fine columnar features to serve as rapid diffusion paths. The latter two accelerated oxidation processes could only be discerned through the use of TEM techniques. They provide a critical step necessary for pest reactions, in addition to structural defects, for the NbAl_3 and MoSi_2 intermetallic compounds, as originally proposed by Doychak and co-workers.

Summary and Conclusions

This study has documented some unusual behavior observed during the oxidation of highly sulfur-doped NiAl. While the presence of Zr dopants did result in numerous Zr-S precipitates due to the gettering ability of Zr, no additional information was provided that directly impacts scale adhesion theory or the sulfur effect. Instead, instances of rapid, linear, nonprotective oxidation were found, even though $\alpha\text{-Al}_2\text{O}_3$ was the primary scale phase. In the case of the S/Zr co-doped NiAl, the scale grew with an unstable interface geometry into a hypostoichiometric $\beta\text{-NiAl}$. As islands of metal were encompassed by the advancing front, Al-depletion to levels as low as 10% (down from 50%) was observed, resulting ultimately in local NiAl_2O_4 formation. Final weight gains exceeded 100 mg/cm^2 as would be the case for complete consumption of the sample. The rapid oxidation appeared to result from a porous scale microstructure, where submicron open channels served as paths for rapid gas transport. In one mechanism, it is suggested that the high level of sulfur in the alloy accumulates at the oxidation front, produces local depassivation, evolves SO_2 at a high gas pressure and volume, and is ultimately responsible for these microchannels. If the pores are not continuous, the SO_2 pressures will not be high and this mechanism would not apply.

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TABLE I.—COMPOSITIONS OF SELECTED S/Zr DOPED NiAl ALLOYS
[Atomic percent; or ppma where indicated.]

Alloy number	Ni, XRF	Al, XRF	Zr, XRF	S, XRF	S, Leco	S, GDMS
1	51.4	48.6	0.00 (0.00)	0.00 (0.00)	≤0.0001	0.0001 1.5 ppma
2	51.2	48.8	0.00 (0.00)	0.040 (0.05)	0.024	0.013 130 ppma
3	51.3	48.5	0.160 (0.14)	0.037 (0.14)	0.039	0.032 320 ppma

(Melt addition).

TABLE II.—MICROPROBE ANALYSIS OF
SULFUR-DOPED NiAl+Zr (atomic %)
[NiAl-3, 0.14 Zr + 0.14 S.]

	Ni	Al	Zr	S	S/Zr
undoped NiAl-1	48	52	0.01	0.05	
NiAl-3 matrix	48	52	0.03	0.05	
network	48	52	0.02	0.01	
precipitates:					
rectangular (g)	47	33	20	0.2	0.01
elliptical (c1)	44	34	18	0.2	0.01
elliptical (c2)	44	34	23	4.4	0.16
fine cluster (f)	43	45	8	4.2	0.55
stringer (d)	37	32	22	8.4	0.39

TABLE III.—XRD ANALYSIS OF SCALE PHASES,
1200 °C, IN AIR

Alloy	Cyclic, 200 hr	Interrupted, 500 hr
NiAl-1	Al ₂ O ₃	Al ₂ O ₃
NiAl-6	Al ₂ O ₃	Al ₂ O ₃
NiAl-3	NiAl ₂ O ₄ , Al ₂ O ₃	NiAl ₂ O ₄ , Al ₂ O ₃ , (ZrO ₂ , NiO)

TABLE IV.—EDS ANALYSIS OF METAL AND SCALE
PHASES, NiAl-3: 0.14 S, 0.14 Zr; 10 hr at 1200 °C
[Atomic percent, standardless ZAF corrections.]

	Ni	Al	O	Phase
6 kV, no carbon				
Bright metal islands	75 to 85	5 to 15	10	γ-Ni-10Al
Interface metal, <10 μm	64	26	0.5	γ'-Ni-29Al
In depletion zone, 30 μm	54.6	30.25	0.7	β-Ni-35Al
Out of depletion, 230 μm	44.1	42.3	4.6	β-Ni-49Al
Centerline	47.8	44.8	3.2	β-Ni-48Al
Dark alumina matrix	0.4	36	63	Al ₂ O _{3.5}
Grey spinel islands	16	22	62	NiO·Al ₂ O ₄
10 kV, carbon coat				
Dark alumina matrix	---	45	55	Al ₂ O _{2.5}
Grey spinel islands	14	33	53	NiO·Al ₂ O _{2.4}



SEM/BSE, 250x



SEM/BSE, 3000x

Figure 1.—As-cast microstructures. NiAl-3, 0.14 Zr + 0.14 S. Bright network and dispersed Zr-rich Ni_2AlZr precipitates.

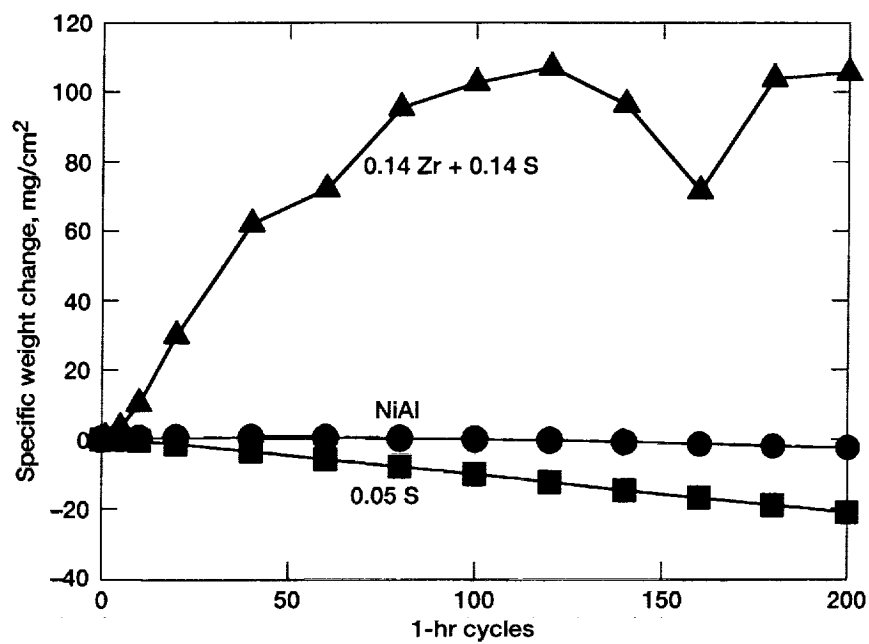


Figure 2.—Effect of sulfur doping on 1200 °C cyclic oxidation.

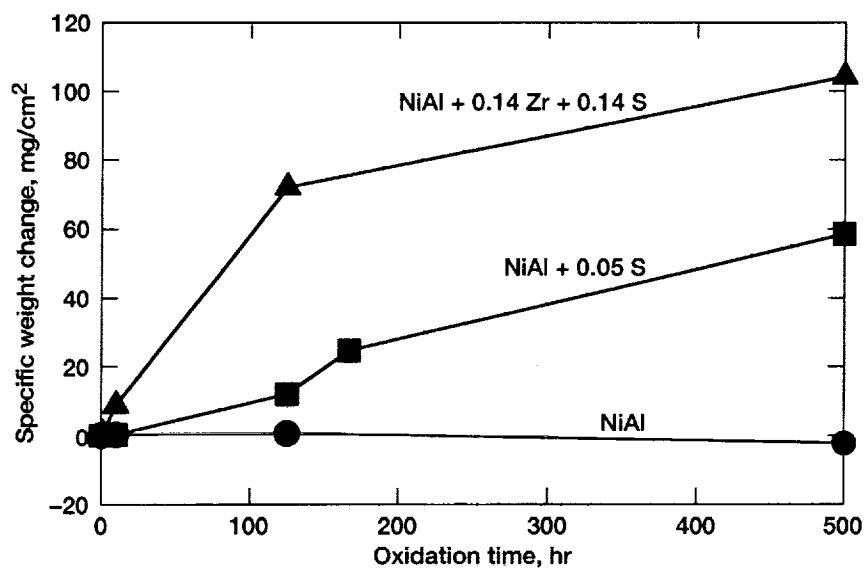
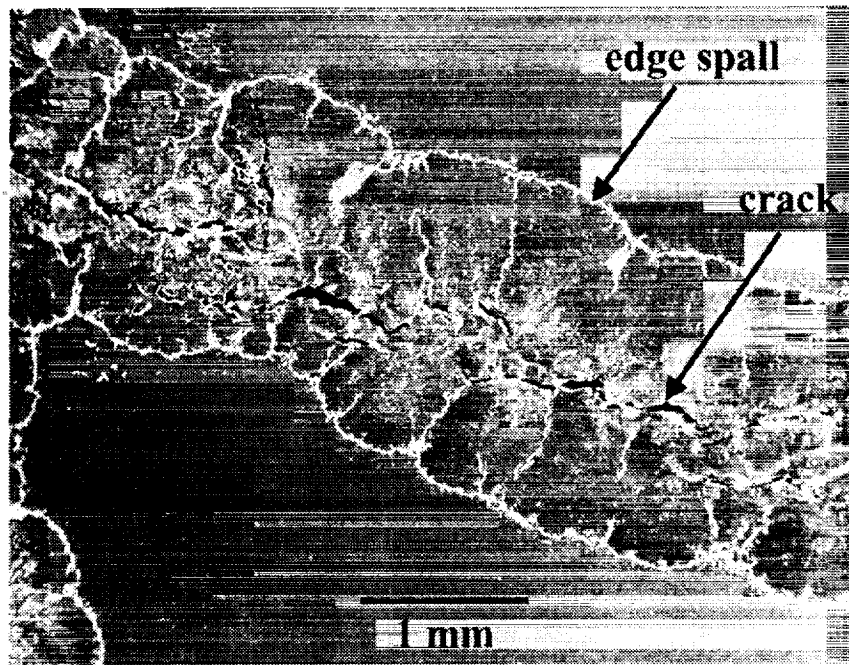
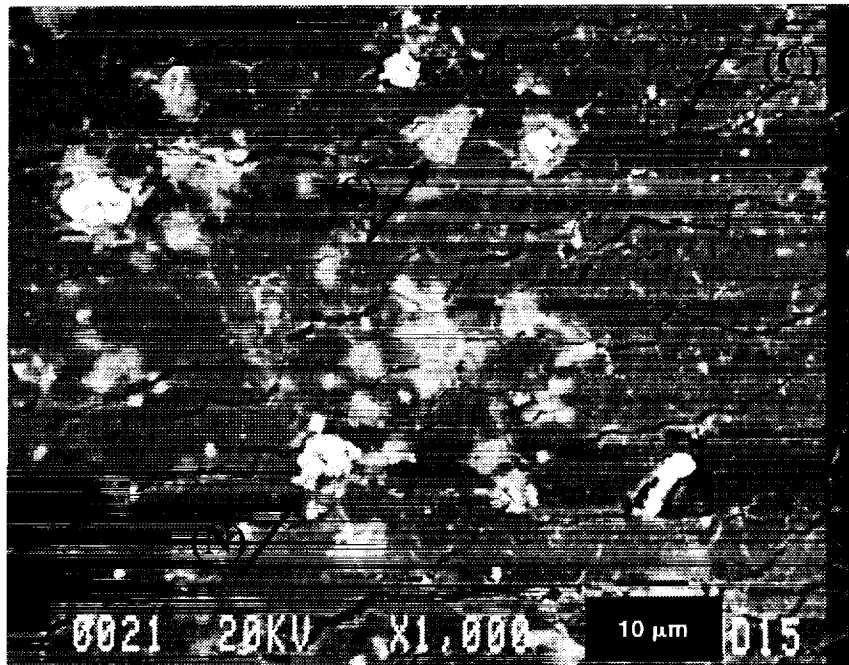


Figure 3.—Effect of sulfur doping on 1200 °C interrupted oxidation.



SEM/SE, 20x initiation ridge



SEM/BSE, 1000x local NiO and NiAl₂O₄ regions

Figure 4.—Incipient degradation of NiAl-3, 0.14 Zr + 0.14 S; 10 hr at 1200 °C. Swelling, cracking, spalling, and Ni-oxide formation.

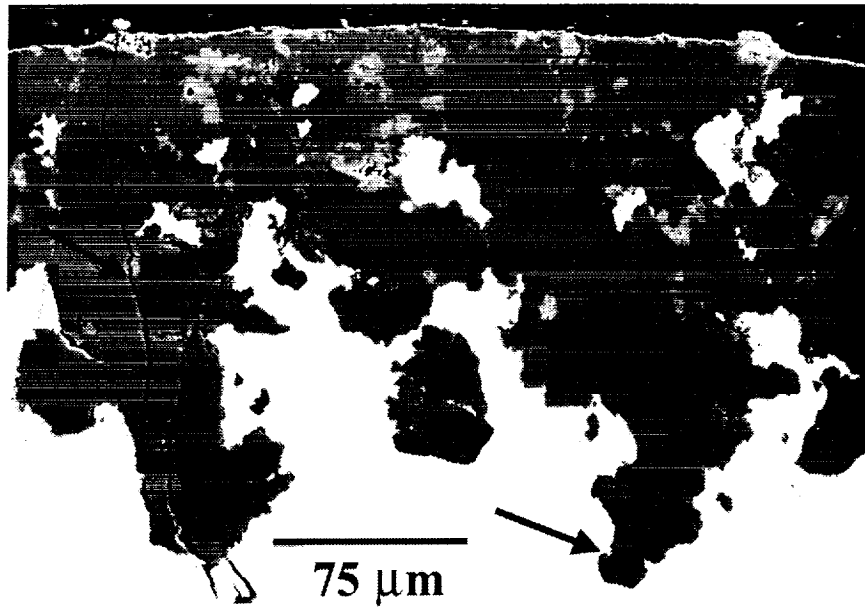


Figure 5.—Fractal intrusions and cracking at mid-spline of oxide ridge. NiAl-3: 0.14 Zr + 0.14 S; 1200 °C, 10 hr.



Figure 6.—Entrapped Ni, Ni-Al-O regions. NiAl-3: 0.14 Zr + 0.14 S; 1200 °C, 10 hr.

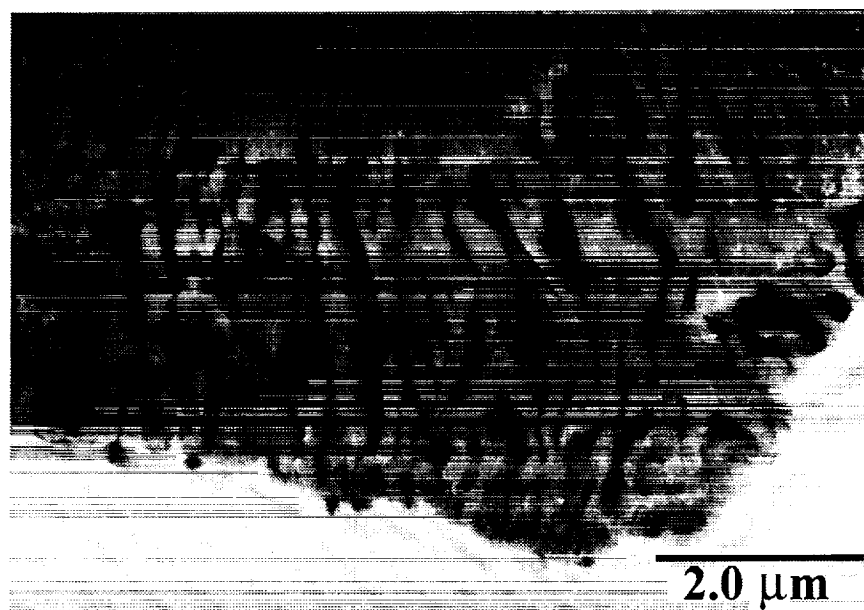
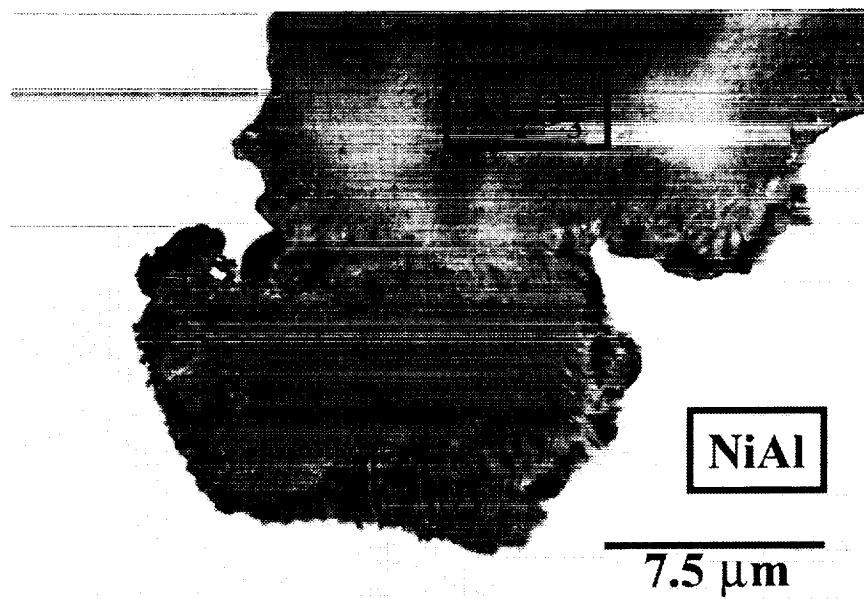
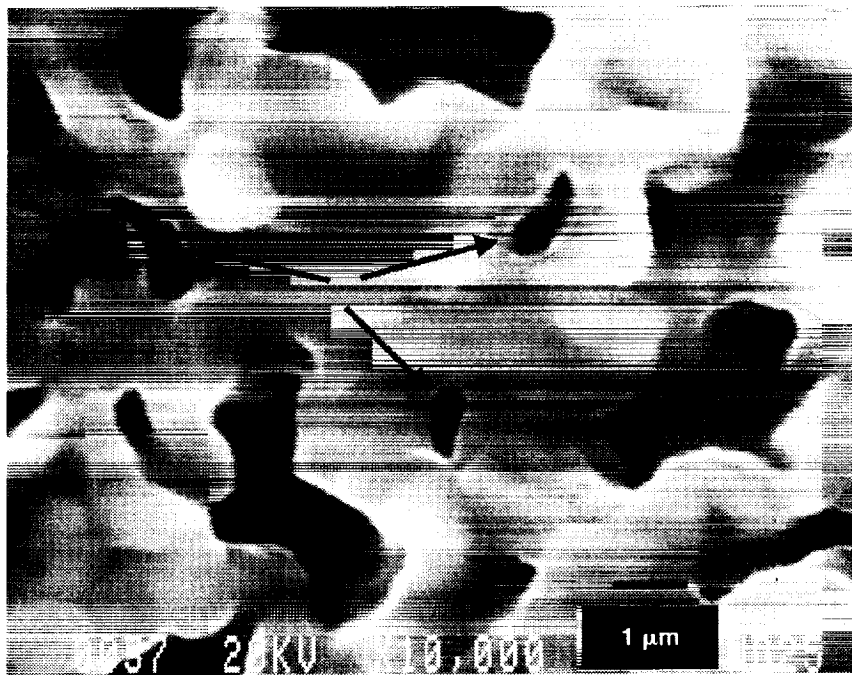


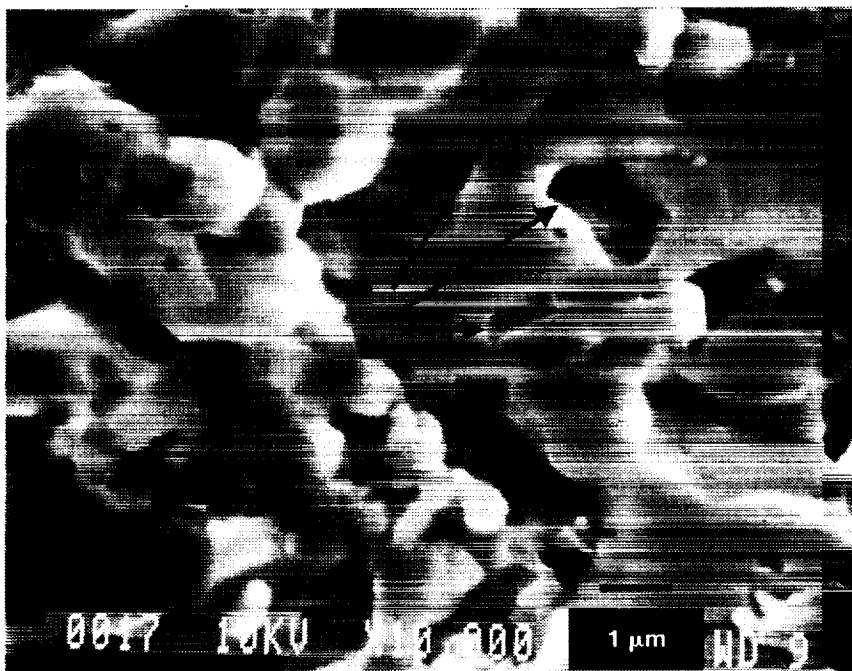
Figure 7.—Tip of fibrous Al_2O_3 intrusion. NiAl-3: 0.14 Zr + 0.14 S; 1200 °C, 10 hr.



Figure 8.— Al_2O_3 microchannels. NiAl-3: 0.14 Zr + 0.14 S; 1200 °C, 10 hr.



SEM/SE, 10 000x top surface of scale



SEM/SE, 10 000x bottom of stripped scale

Figure 9.—Porous surfaces of unprotective Al_2O_3 scales. NiAl-6, 0.05 S; 1200 °C, 125 hr.

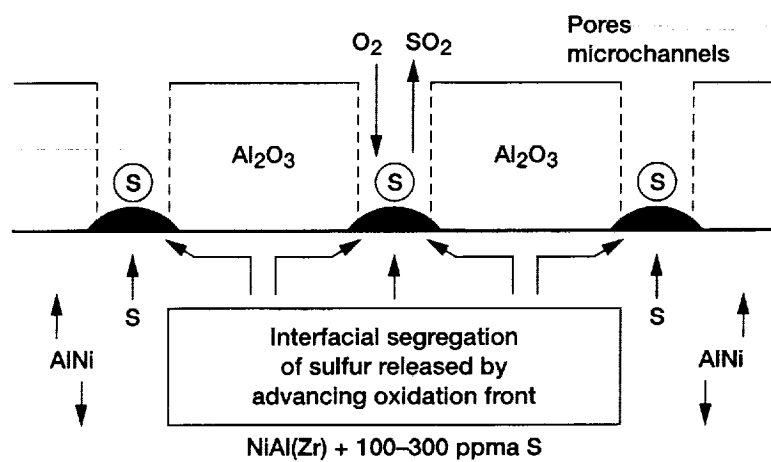


Figure 10.—Sulfur accumulation and gas generation model.



Figure 11.—Microporosity in Al_2O_3 scale on AlN. 10% $\text{H}_2\text{O/O}_2$, 1200 °C, 48 hr; Opila 1999 (ref. 17).

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13. ABSTRACT (Maximum 200 words) The 1200°C oxidation behavior of NiAl was examined at various levels of sulfur and zirconium dopants to test the possibility of a critical S/Zr ratio required for adhesion. Cyclic furnace testing for 200 1-hr cycles and interrupted testing for 500 hr were used as screening tests. Pure NiAl and NiAl(Zr) with 0.14 at.% Zr were chosen as model base compositions; they exhibited normal, slow-growing scales (3 mg·cm ⁻²) with excellent adhesion for the Zr-doped alloys. NiAl with about 120 ppma S exhibited a substantial weight loss (-20 mg·cm ⁻²) in cyclic tests and a very large weight gain (+60 mg·cm ⁻²) in interrupted tests. The major surface phase remained as α-Al ₂ O ₃ . Sulfur doping the NiAl(Zr) alloy caused massive weight gains of 80-100 mg·cm ⁻² , swelling, cracking, and nearly complete conversion into NiAl ₂ O ₄ and α-Al ₂ O ₃ . The initial objective of determining critical S/Zr ratios for adhesion was therefore unattainable. Initiation of the catastrophic attack was examined after a 10 hr exposure, revealing a few sites of broad, raised, and cracked ridges. In cross-section, the ridges appeared as nodular intrusions, with a complex, fractal, oxide-metal interface. They were primarily alumina (with occasional entrapped islands of NiAl ₂ O ₄ or pure Ni metal). They possessed a unique microstructure consisting of 0.3 μm lamellae, separated by 0.1 μm open channels. This allowed for rapid growth controlled by gaseous diffusion. The microstructure is discussed in terms of SO ₂ evolution and a sulfur-driven de-passivation process.				
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